

EMP104

ISSUED DATE: 07-12-04

FEATURES

- 5.0 6.5 GHz Operating Frequency Range
- 33.0dBm Output Power at 1dB Compression
- 17.0 dB Typical Small Signal Gain
- -40dBc OIMD3 @Each Tone Pout 22dBm

APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems

5.0 – 6.5 GHz Power Amplifier MMIC

Dimension: 2200um X 3230um Thickness: 65um <u>+</u> 15um



Caution! ESD sensitive device.

ELECTRICAL CHARACTERISTICS (Ta = 25 °C, 50 ohm, VDD=10V, IDQ=1000mA)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	5.0		6.5	GHz
P1dB	Output Power at 1dB Gain Compression	32.0	33.0		dBm
Gss	Small Signal Gain	15.0	17.0		dB
OIMD3	Output 3 rd Order Intermodulation Distortion @∆f=10MHz, Each Tone Pout 22dBm		-40		dBc
Input RL	Input Return Loss		-8	-6	dB
Output RL	Output Return Loss		-6		dB
ldss	Saturate Drain Current $V_{DS} = 3V, V_{GS} = 0V$		1680		mA
V _{DD}	Power Supply Voltage		10		V
Rth	Thermal Resistance (Au-Sn Eutectic Attach)		7		°C/W
Tb	Operating Base Plate Temperature	- 35		+ 80	°C

ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION^{1,2}

SYMBOL	CHARACTERISTIC	VALUE	
V _{DS}	Drain to Source Voltage	10V	
V_{GS}	Gate to Source Voltage	- 4V	
I _{DD}	Drain Current	ldss	
I _{GSF}	Forward Gate Current	35 mA	
P _{IN}	Input Power	@ 3dB compression	
Т _{СН}	Channel Temperature	150°C	
T _{STG}	Storage Temperature	-65/150°C	
Ρ _T	Total Power Dissipation	17W	

1. Operating the device beyond any of the above rating may result in permanent damage.

2. Bias conditions must also satisfy the following equation $V_{DS}*I_{DS} < (T_{CH} - T_{HS})/R_{TH}$; where T_{HS} = ambient temperature

Specifications are subject to change without notice. Excelics Semiconductor, Inc. 310 De Guigne Drive, Sunnyvale, CA 94085 Phone: 408-737-1711 Fax: 408-737-1868 Web: www.excelics.com

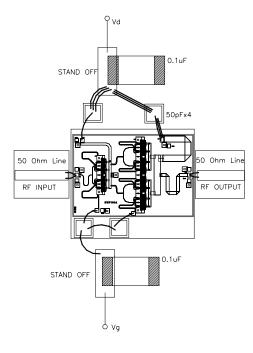


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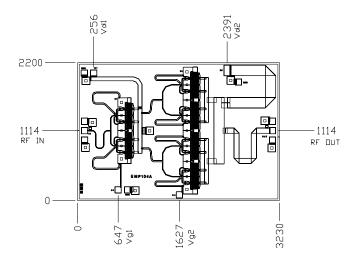
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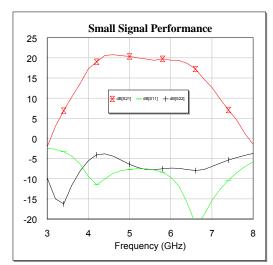
ASSEMBLY DRAWING



CHIP OUTLINE

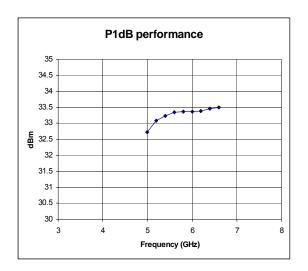


All Dimensions in Microns



TYPICAL PERFORMANCE

Data measured @ Vd=10V, Id=950mA



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